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TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX138F,TC74LCX138FN,TC74LCX138FT,TC74LCX138FK

Low-Voltage 3-to-8 Line Decoder with 5-V Tolerant Inputs and Outputs

The TC74LCX138F/FN/FT/FK is a high-performance CMOS 3-to-8 decoder. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low-power dissipation.

The device is designed for low-voltage $(3.3 \text{ V}) \text{ V}_{CC}$ applications, but it could be used to interface to 5-V supply environment for inputs.

When the device is enabled, 3 binary select inputs (A, B and C) determine which one of the outputs $(\overline{Y0} - \overline{Y7})$ will go low. When enable input G1 is held low or either $\overline{G}2A$ or $\overline{G}2B$ is held high, decoding function is inhibited and all outputs go high.

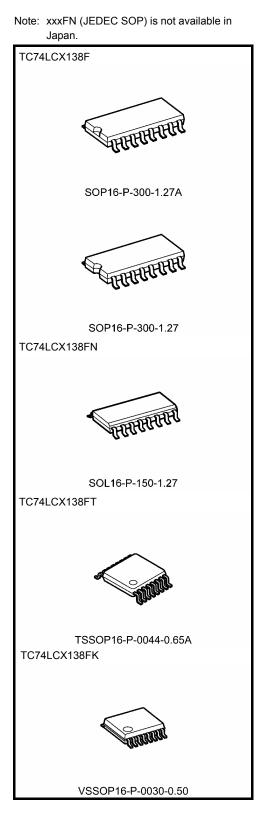
G1, $\overline{G}2A$, and $\overline{G}2B$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

All inputs are equipped with protection circuits against static discharge.

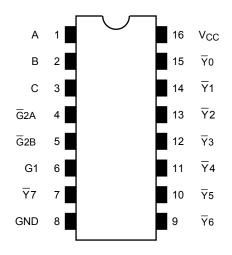
Features

- Low-voltage operation: $V_{CC} = 2.0$ to 3.6 V
- High-speed operation: $t_{pd} = 6.0 \text{ ns} (max) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Ouput current: $|I_{OH}|/I_{OL} = 24 \text{ mA} (min) (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- Available in JEDEC SOP, JEITA SOP and TSSOP
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 138 type

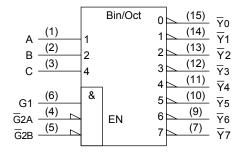
Weight	
SOP16-P-300-1.27A	: 0.18 g (typ.)
SOP16-P-300-1.27	: 0.18 g (typ.)
SOL16-P-150-1.27	: 0.12 g (typ.)
TSSOP16-P-0044-0.65A	: 0.06 g (typ.)
VSSOP16-P-0030-0.50	: 0.02 g (typ.)

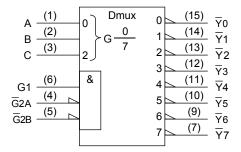


Pin Assignment (top view)



IEC Logic Symbol





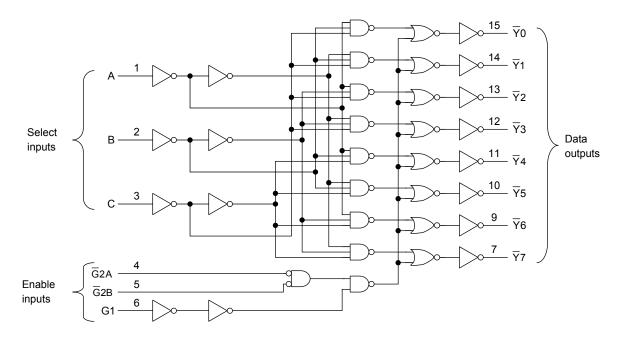
Truth Table

Inputs					Outputs									
	Enable			Select		- Y0	T ₁	T ₂	¥3	¥4	¥5	¥6	T7	Selected Output
G1	G2A	G2B	С	В	А	10	TI	12	13	14	15	10	17	
L	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None
Х	Н	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None
Х	Х	Н	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None
Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	Υ 0
Н	L	L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	<u>¥</u> 1
Н	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н	¥2
Н	L	L	L	Н	Н	Н	Н	Н	L	Н	н	Н	Н	<u>¥</u> 3
Н	L	L	Н	L	L	Н	Н	Н	Н	L	н	Н	Н	$\overline{Y}4$
Н	L	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	¥5
Н	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Υ 6
Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L	¥7

X: Don't care

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System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	–0.5 to 7.0	V	
DC input voltage	V _{IN}	–0.5 to 7.0	V	
		-0.5 to 7.0 (Note 2)	V	
DC output voltage	Vout	-0.5 to V _{CC} + 0.5 (Note 3)		
Input diode current	IIK	-50	mA	
Output diode current	I _{OK}	±50 (Note 4)	mA	
DC output current	IOUT	±50	mA	
Power dissipation	PD	180	mW	
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA	
Storage temperature	T _{stg}	–65 to 150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

- Note 2: $V_{CC} = 0 V$
- Note 3: High or low state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.
- Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Recommended Operating Conditions (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	2.0 to 3.6	V	
Tower supply voltage	v CC	1.5 to 3.6 (Note 2)	v	
Input voltage	V _{IN}	0 to 5.5	V	
Output voltage	Vour	0 to 5.5 (Note 3)	V	
Output voltage	Vout	0 to V _{CC} (Note 4)		
Output current	Іон/Іог	±24 (Note 5)	mA	
Output current	'OH/'OL	±12 (Note 6)	ШA	
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V	

Note 1: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

- Note 3: $V_{CC} = 0 V$
- Note 4: High or low state
- Note 5: $V_{CC} = 3.0$ to 3.6 V
- Note 6: $V_{CC} = 2.7$ to 3.0 V
- Note 7: $V_{IN}=0.8$ to 2.0 V, $V_{CC}=3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

Characteristics		Symbol	Test Condition			Min	Max	Unit
	H-level	VIH	_	2.7 to 3.6	2.0	_	V	
Input voltage	L-level	V _{IL}	_	-	2.7 to 3.6	_	0.8	v
			$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -100 \ \mu A$	2.7 to 3.6	V _{CC} -0.2		
	H-level	V _{OH}		I _{OH} = -12 mA	2.7	2.2	_	V
				I _{OH} = -18 mA	3.0	2.4	_	
Output voltage				I _{OH} = -24 mA	3.0	2.2		
	L-level	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 100 \ \mu A$	2.7 to 3.6	—	0.2	
				$I_{OL} = 12 \text{ mA}$	2.7	—	0.4	
				I _{OL} = 16 mA	3.0	—	0.4	
				$I_{OL} = 24 \text{ mA}$	3.0	_	0.55	
Input leakage current		I _{IN}	V _{IN} = 0 to 5.5 V		2.7 to 3.6	—	±5.0	μA
Power-off leakage current		IOFF	$V_{IN}/V_{OUT} = 5.5 V$		0	—	10.0	μA
Quiescent supply current		ICC	$V_{IN} = V_{CC}$ or GND		2.7 to 3.6	—	10.0	
			$V_{IN} = 3.6$ to 5.5 V	2.7 to 3.6	—	±10.0	μA	
Increase in Icc per inp	ut	Δlcc	$V_{IH} = V_{CC} - 0.6 \ V$		2.7 to 3.6	_	500	

AC Characteristics (Ta = -40 to 85°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	7.0	ns
(A, B, C- <u>Y</u>)	t _{pHL}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	6.0	113
Propagation delay time t _{pLH} Figure 1, Figure 2	Figure 1 Figure 2	2.7	_	8.0	20	
(G1- <u>Y</u>)	t _{pHL}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	7.0	ns
Propagation delay time	t _{pLH}	Figure 1 Figure 2	2.7	_	7.0	ns
(<u>G</u> 2 - <u>Y</u>)	t _{pHL}	Figure 1, Figure 2	$\textbf{3.3}\pm\textbf{0.3}$	1.5	6.0	115
Output to output skew	t _{osLH}	(Neto)	2.7	_	_	20
	t _{osHL}	(Note) -	$\textbf{3.3}\pm\textbf{0.3}$	—	1.0	ns

Note: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V_{OL}	V _{OLP}	$V_{IH} = 3.3 V, V_{IL} = 0 V$	3.3	0.8	V
Quiet output minimum dynamic V_{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

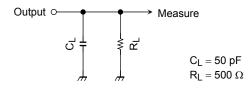
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	—	3.3	7	pF
Output capacitance	C _{OUT}		0	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Note) 3.3	25	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

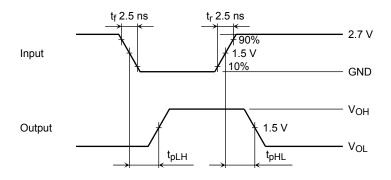
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

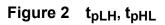
AC Test Circuit





AC Waveform



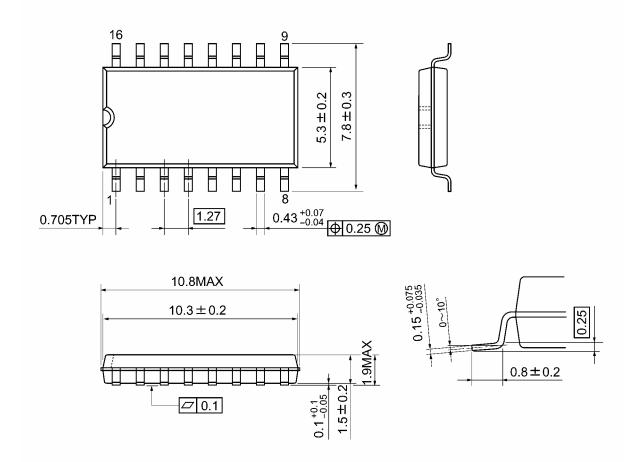




Package Dimensions

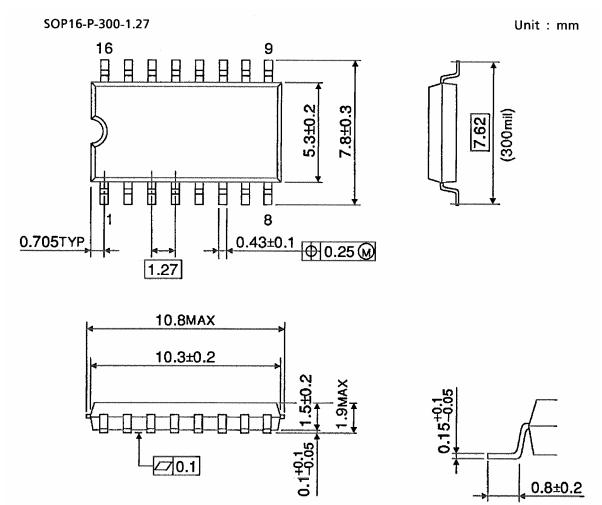
SOP16-P-300-1.27A

Unit: mm



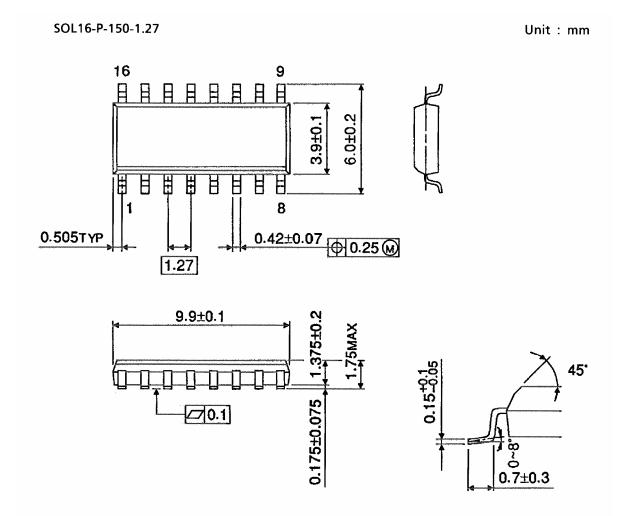
Weight: 0.18 g (typ.)

Package Dimensions



Weight: 0.18 g (typ.)

Package Dimensions (Note)



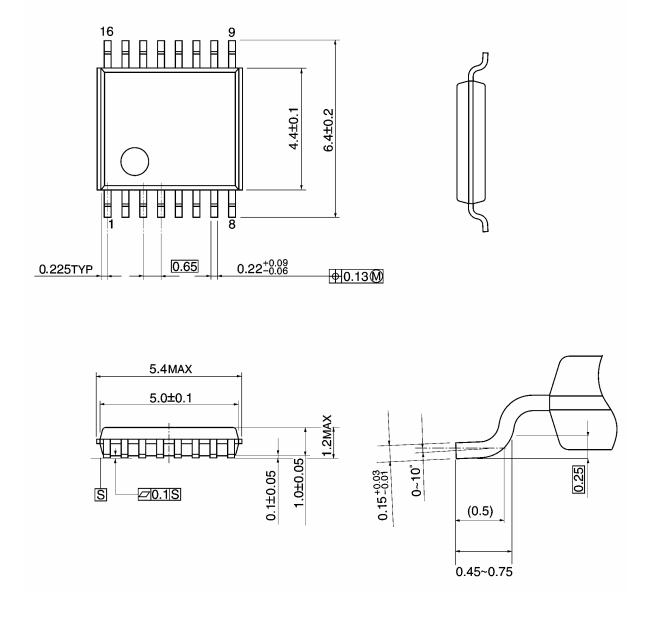
Note: This package is not available in japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm



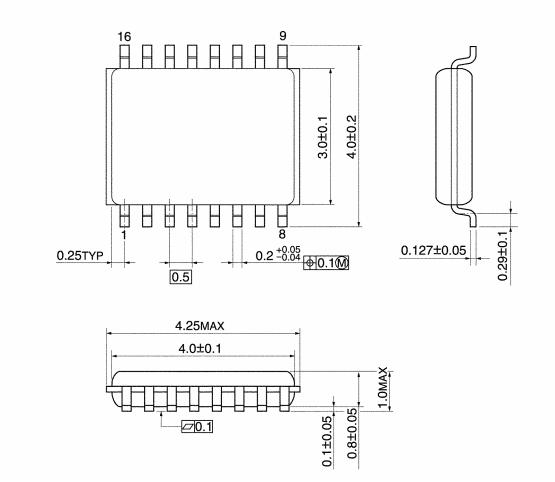
Weight: 0.06 g (typ.)

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Package Dimensions

VSSOP16-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

Note: Lead (Pb)-Free Packages

SOP16-P-300-1.27A SOL16-P-150-1.27 TSSOP16-P-0044-0.65A VSSOP16-P-0030-0.50

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